

# GD2X30MPS06N 650V 60A SiC Schottky MPS™ Diode



## Silicon Carbide Schottky Diode

$V_{RRM}$	=	650 V
$I_F (T_C = 116^\circ\text{C})$	=	60 A *
$Q_C$	=	92 nC *

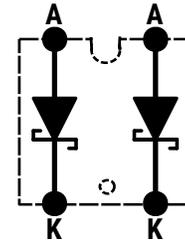
### Features

- Gen4 Thin Chip Technology for Low  $V_F$
- Superior Power Efficiency
- Superior Figure of Merit  $Q_C/I_F$
- Enhanced Surge Current Robustness
- Low Thermal Resistance
- Temperature Independent Fast Switching
- Positive Temperature Coefficient of  $V_F$
- High  $dV/dt$  Ruggedness

### Package



SOT-227



### Advantages

- Optimal Price Performance
- Improved System Efficiency
- Reduced Cooling Requirements
- Increased System Power Density
- Zero Reverse Recovery Current
- High System Reliability
- Easy to Parallel without Thermal Runaway
- Enables Extremely Fast Switching

### Applications

- Power Factor Correction (PFC)
- Electric Vehicles and Battery Chargers
- Solar Inverters
- High Frequency Converters
- Switched Mode Power Supply (SMPS)
- Motor Drives
- Anti-Parallel / Free-Wheeling Diode
- Induction Heating & Welding

### Absolute Maximum Ratings (At $T_C = 25^\circ\text{C}$ Unless Otherwise Stated)

Parameter	Symbol	Conditions	Values	Unit	Note
Repetitive Peak Reverse Voltage (Per Leg)	$V_{RRM}$		650	V	
Continuous Forward Current (Per Leg / Per Device)	$I_F$	$T_C = 75^\circ\text{C}, D = 1$	42 / 84	A	Fig. 4
		$T_C = 100^\circ\text{C}, D = 1$	35 / 70		
		$T_C = 116^\circ\text{C}, D = 1$	30 / 60		
Non-Repetitive Peak Forward Surge Current, Half Sine Wave (Per Leg)	$I_{F,SM}$	$T_C = 25^\circ\text{C}, t_P = 10 \text{ ms}$	210	A	
		$T_C = 150^\circ\text{C}, t_P = 10 \text{ ms}$	168		
Repetitive Peak Forward Surge Current, Half Sine Wave (Per Leg)	$I_{F,RM}$	$T_C = 25^\circ\text{C}, t_P = 10 \text{ ms}$	126	A	
		$T_C = 150^\circ\text{C}, t_P = 10 \text{ ms}$	89		
Non-Repetitive Peak Forward Surge Current (Per Leg)	$I_{F,MAX}$	$T_C = 25^\circ\text{C}, t_P = 10 \mu\text{s}$	1050	A	
$i^2t$ Value (Per Leg)	$\int i^2 dt$	$T_C = 25^\circ\text{C}, t_P = 10 \text{ ms}$	220	$\text{A}^2\text{s}$	
Non-Repetitive Avalanche Energy (Per Leg)	$E_{AS}$	$L = 0.6 \text{ mH}, I_{AS} = 30 \text{ A}$	276	mJ	
Diode Ruggedness (Per Leg)	$dV/dt$	$V_R = 0 \sim 520 \text{ V}$	200	V/ns	
Power Dissipation (Per Leg / Per Device)	$P_{TOT}$	$T_C = 25^\circ\text{C}$	136 / 272	W	Fig. 3
Operating and Storage Temperature	$T_j, T_{stg}$		-55 to 175	$^\circ\text{C}$	

\* Per Device

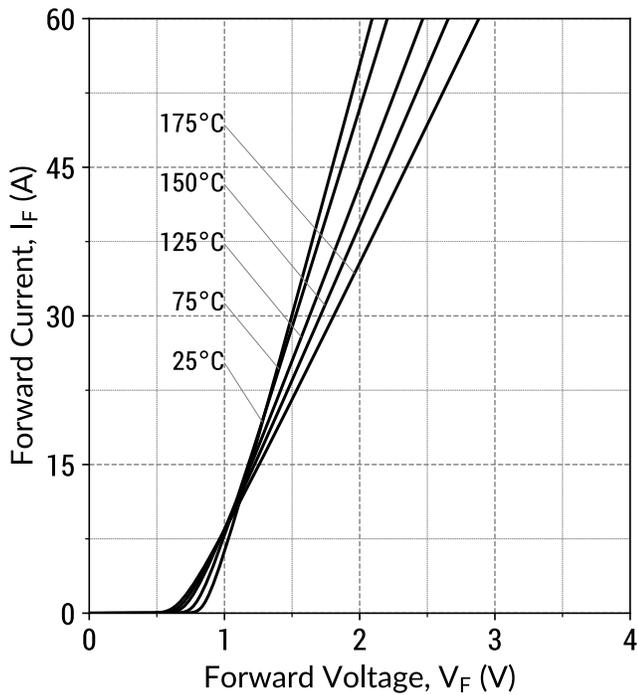
### Electrical Characteristics (Per Leg)

Parameter	Symbol	Conditions	Values			Unit	Note
			Min.	Typ.	Max.		
Diode Forward Voltage	$V_F$	$I_F = 30\text{ A}, T_j = 25^\circ\text{C}$		1.5	1.8	V	Fig. 1
		$I_F = 30\text{ A}, T_j = 175^\circ\text{C}$		1.8			
Reverse Current	$I_R$	$V_R = 650\text{ V}, T_j = 25^\circ\text{C}$		1	5	$\mu\text{A}$	Fig. 2
		$V_R = 650\text{ V}, T_j = 175^\circ\text{C}$		6			
Total Capacitive Charge	$Q_C$	$I_F \leq I_{F,MAX}$ $df/dt = 200\text{ A}/\mu\text{s}$	$V_R = 200\text{ V}$	31		nC	Fig. 7
			$V_R = 400\text{ V}$	46			
Switching Time	$t_s$	$df/dt = 200\text{ A}/\mu\text{s}$	$V_R = 200\text{ V}$	< 10		ns	
			$V_R = 400\text{ V}$				
Total Capacitance	C	$V_R = 1\text{ V}, f = 1\text{MHz}$		735		pF	Fig. 6
		$V_R = 400\text{ V}, f = 1\text{MHz}$		63			

### Thermal/Package Characteristics

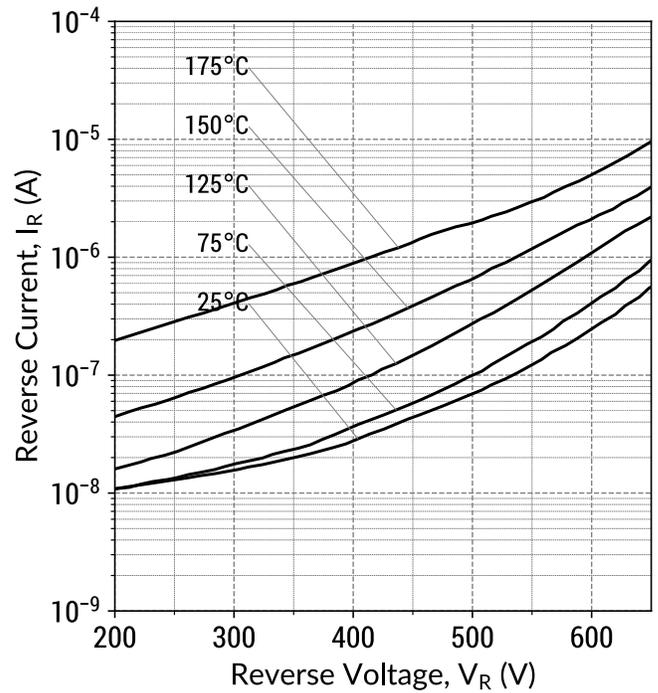
Parameter	Symbol	Conditions	Values			Unit	Note
			Min.	Typ.	Max.		
Thermal Resistance, Junction - Case (Per Leg)	$R_{thJC}$			1.1		$^\circ\text{C}/\text{W}$	Fig. 9
Weight	$W_T$			28.0		g	
Mounting Torque	$T_M$	Screws to Heatsink			1.5	Nm	
Terminal Connection Torque	$T_C$	M4 Screws			1.3	Nm	
Isolation Voltage(RMS)	$V_{iso}$	$t = 1\text{ s (50/60 Hz)}$		3000		V	
		$t = 60\text{ s (50/60 Hz)}$		2500			
Creepage Distance on Surface	$d_{ctt}$	Terminal to Terminal		10.5		mm	
	$d_{ctb}$	Terminal to Backside		8.5			
Striking Distance Through Air	$d_{stt}$	Terminal to Terminal		3.2		mm	
	$d_{stb}$	Terminal to Backside		6.8			

Figure 1: Typical Forward Characteristics (Per Leg)



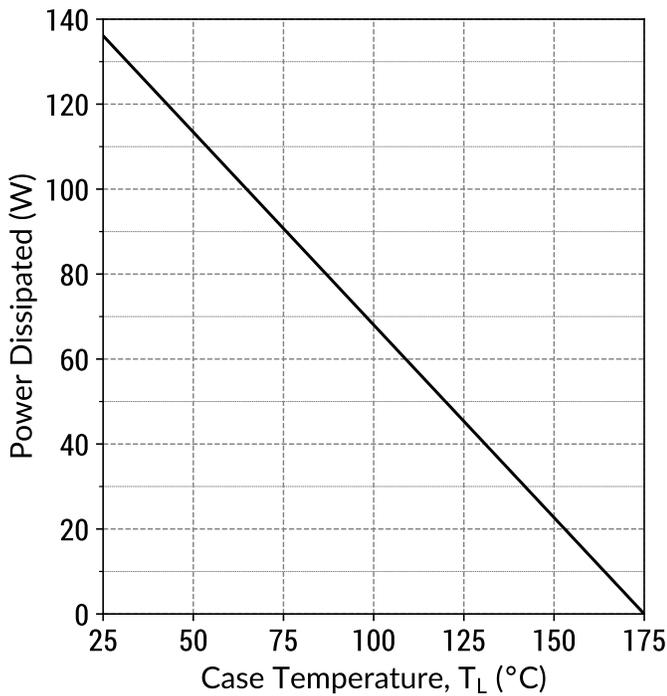
$$I_F = f(V_F, T_j); t_P = 250 \mu s$$

Figure 2: Typical Reverse Characteristics (Per Leg)



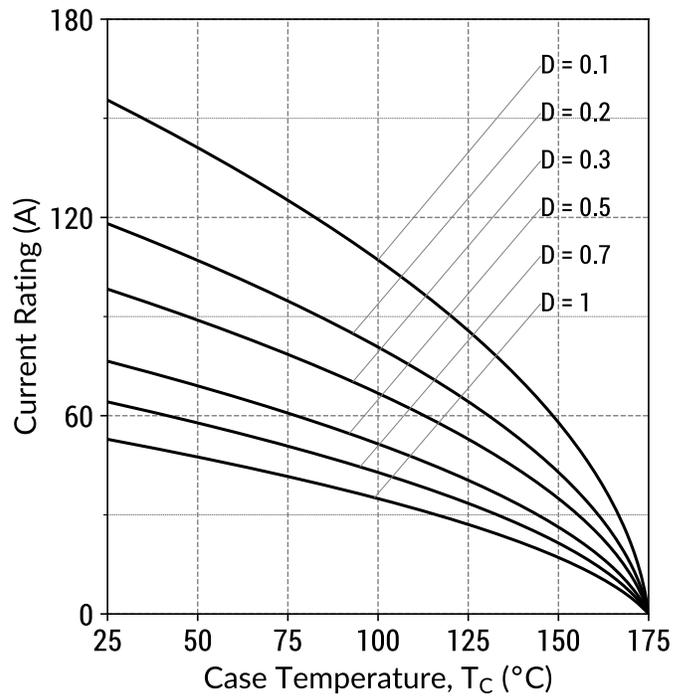
$$I_R = f(V_R, T_j)$$

Figure 3: Power Derating Curves (Per Leg)



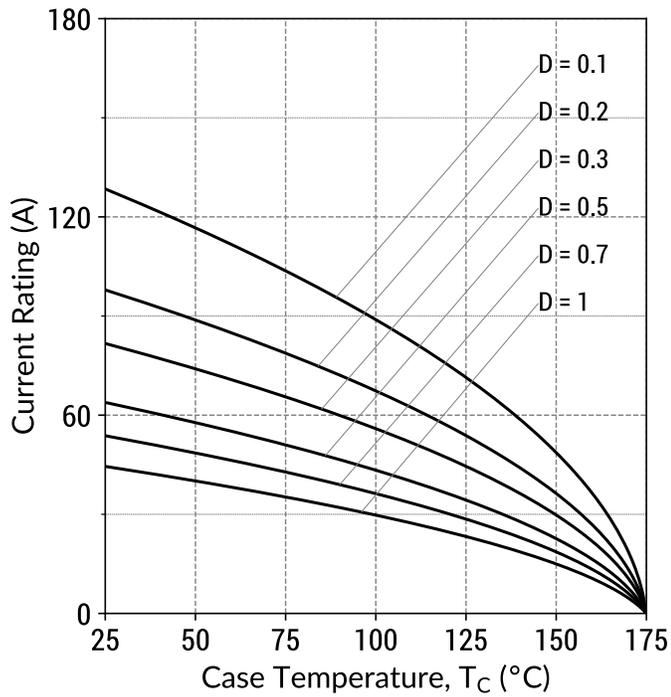
$$P_{TOT} = f(T_C); T_j = 175^\circ C$$

Figure 4: Current Derating Curves (Typical V\_F) (Per Leg)



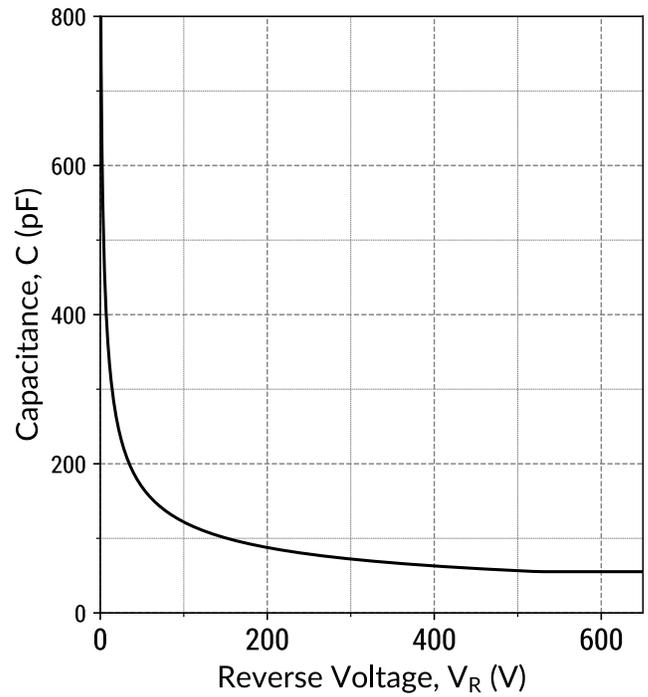
$$I_F = f(T_C); D = t_P/T; T_j \leq 175^\circ C; f_{sw} > 10 kHz$$

Figure 5: Current Derating Curves (Maximum  $V_F$ ) (Per Leg)



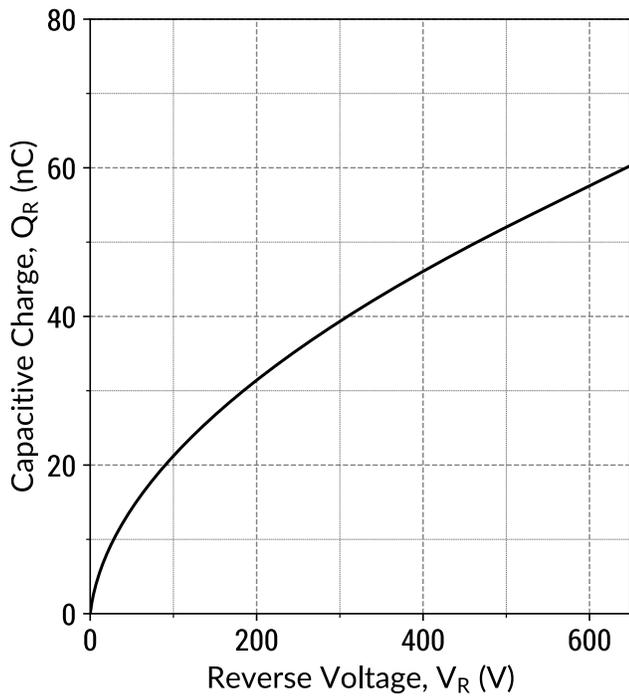
$I_F = f(T_C)$ ;  $D = t_P/T$ ;  $T_J \leq 175^\circ\text{C}$ ;  $f_{SW} > 10\text{kHz}$

Figure 6: Typical Junction Capacitance vs Reverse Voltage Characteristics (Per Leg)



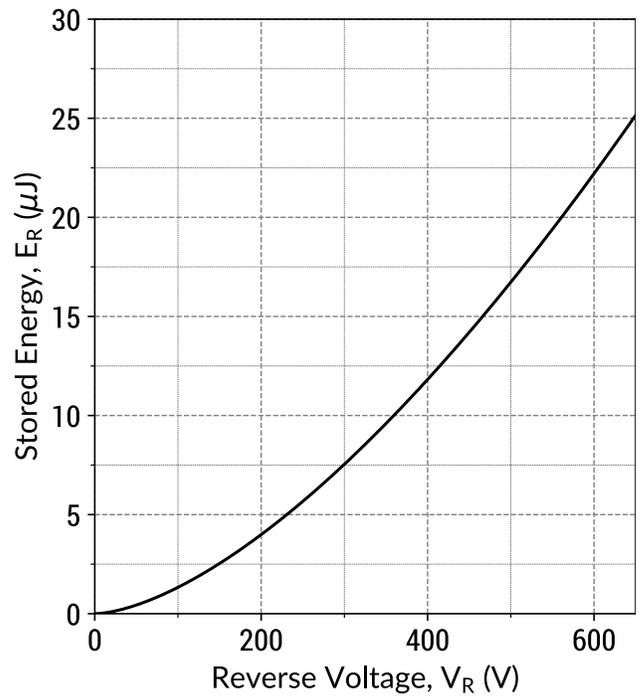
$C = f(V_R)$ ;  $f = 1\text{MHz}$

Figure 7: Typical Capacitive Charge vs Reverse Voltage Characteristics (Per Leg)



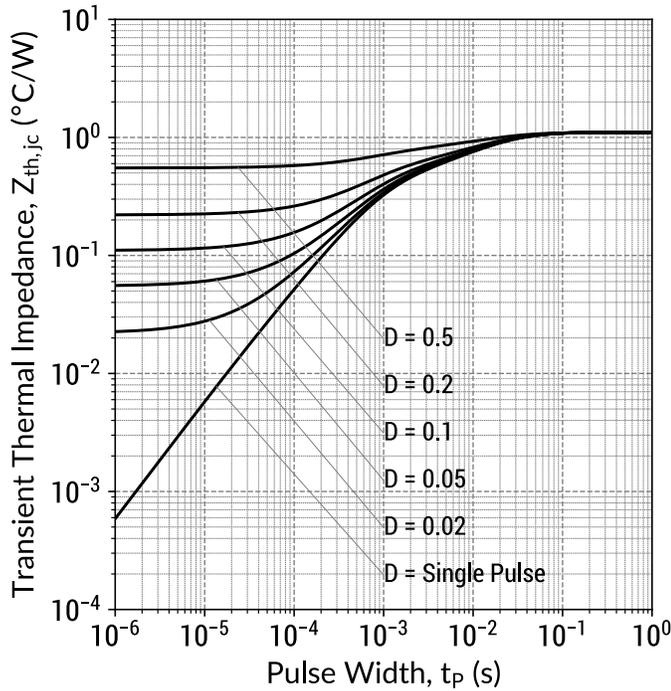
$Q_C = f(V_R)$ ;  $f = 1\text{MHz}$

Figure 8: Typical Capacitive Energy vs Reverse Voltage Characteristics (Per Leg)



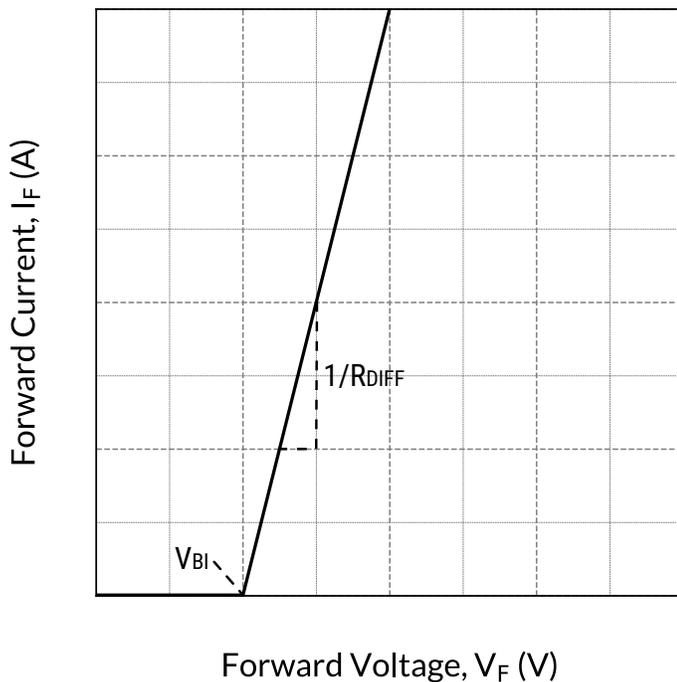
$E_C = f(V_R)$ ;  $f = 1\text{MHz}$

Figure 9: Transient Thermal Impedance (Per Leg)



$$Z_{th,jc} = f(t_p, D); D = t_p/T$$

Figure 10: Forward Curve Model (Per Leg)



$$I_F = f(V_F, T_j)$$

**Forward Curve Model Equation:**

$$I_F = (V_F - V_{BI})/R_{DIFF} \text{ (A)}$$

**Built-In Voltage ( $V_{BI}$ ):**

$$V_{BI}(T_j) = m \times T_j + n \text{ (V)}$$

$$m = -0.00115 \text{ (V/°C)}$$

$$n = 9.31e-01 \text{ (V)}$$

**Differential Resistance ( $R_{DIFF}$ ):**

$$R_{DIFF}(T_j) = a \times T_j^2 + b \times T_j + c \text{ (}\Omega\text{)}$$

$$a = 5.07e-07 \text{ (}\Omega\text{/°C}^2\text{)}$$

$$b = 5.5e-06 \text{ (}\Omega\text{/°C)}$$

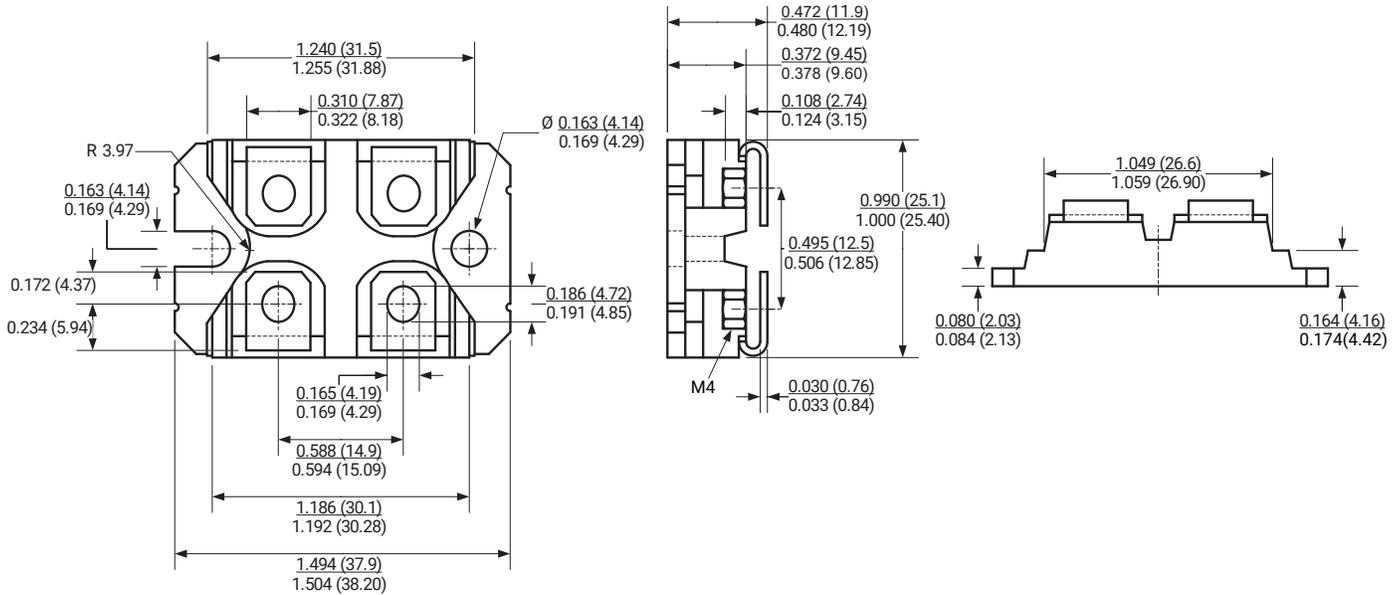
$$c = 0.0194 \text{ (}\Omega\text{)}$$

**Forward Power Loss Equation:**

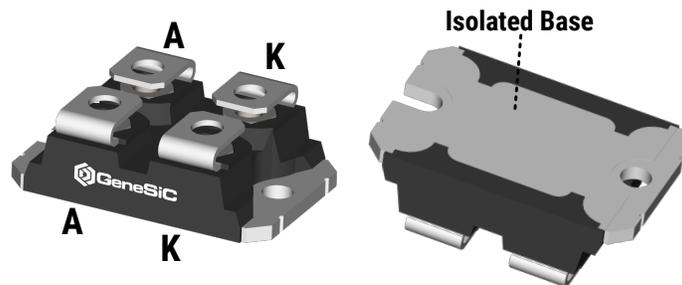
$$P_{LOSS} = V_{BI}(T_j) \times I_{AVG} + R_{DIFF}(T_j) \times I_{RMS}^2$$

Package Dimensions

SOT-227 Package Outline



Package View



NOTE

1. CONTROLLED DIMENSION IS INCH. DIMENSION IN BRACKET IS MILLIMETER.
2. DIMENSIONS DO NOT INCLUDE END FLASH, MOLD FLASH, MATERIAL PROTRUSIONS.

## Compliance

### RoHS Compliance

The levels of RoHS restricted materials in this product are below the maximum concentration values (also referred to as the threshold limits) permitted for such substances, or are used in an exempted application, in accordance with EU Directive 2011/65/EC (RoHS 2), as adopted by EU member states on January 2, 2013 and amended on March 31, 2015 by EU Directive 2015/863. RoHS Declarations for this product can be obtained from your GeneSiC representative.

### REACH Compliance

REACH substances of high concern (SVHCs) information is available for this product. Since the European Chemical Agency (ECHA) has published notice of their intent to frequently revise the SVHC listing for the foreseeable future, please contact a GeneSiC representative to insure you get the most up-to-date REACH SVHC Declaration. REACH banned substance information (REACH Article 67) is also available upon request.

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## Related Links

- SPICE Models: [https://www.genesicsemi.com/sic-schottky-mps/GD2X30MPS06N/GD2X30MPS06N\\_SPICE.zip](https://www.genesicsemi.com/sic-schottky-mps/GD2X30MPS06N/GD2X30MPS06N_SPICE.zip)
- PLECS Models: [https://www.genesicsemi.com/sic-schottky-mps/GD2X30MPS06N/GD2X30MPS06N\\_PLECS.zip](https://www.genesicsemi.com/sic-schottky-mps/GD2X30MPS06N/GD2X30MPS06N_PLECS.zip)
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## Revision History

Date	Revision	Comments	Supersedes
Jul. 27, 2020	Rev 1	Initial Release	



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